NSN 5961-01-480-6069

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-480-6069 **Inclosure Material:** Ceramic **Overall Length:** 3.048 millimeters **Terminal Length:** 2.032 millimeters **Overall Height:** 1.397 millimeters **Overall Width:** 3.277 millimeters **End Application:** Stv camera sy **Mounting Facility Quantity: Mounting Method:** Compression **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 working peak reverse voltage **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current preset and 600.00 milliamperes forward current, average preset and 700.00 milliamperes forward current, average blank **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-emitter peak **Capacitance Rating In Picofarads:** 2.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction and -55.0 degrees celsius junction **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No